

# 933.685

### MAXIMUM RATINGS

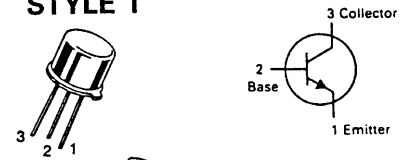
| Rating   | Symbol                            | 2N2219<br>2N2222    | 2N2218A<br>2N2219A<br>2N2222A | Unit           |
|--|-----------------------------------|---------------------|-------------------------------|----------------|
| Collector-Emitter Voltage  | V <sub>CEO</sub>                  | 30                  | 40                            | Vdc            |
| Collector-Base Voltage   | V <sub>CBO</sub>                  | 60                  | 75                            | Vdc            |
| Emitter-Base Voltage   | V <sub>EBO</sub>                  | 5.0                 | 6.0                           | Vdc            |
| Collector Current — Continuous   | I <sub>C</sub>                    | 800                 | 800                           | mAdc           |
|  |                                   | 2N2218A<br>2N2219,A | 2N2222,A                      |                |
| Total Device Dissipation<br>@ T <sub>A</sub> = 25°C<br>Derate above 25°C | P <sub>D</sub>                    | 0.8<br>4.57         | 0.4<br>2.28                   | Watt<br>mW/°C  |
| Total Device Dissipation<br>@ T <sub>C</sub> = 25°C<br>Derate above 25°C | P <sub>D</sub>                    | 3.0<br>17.1         | 1.2<br>6.85                   | Watts<br>mW/°C |
| Operating and Storage Junction<br>Temperature Range                      | T <sub>J</sub> , T <sub>stg</sub> | -65 to +200         |                               | °C             |

### THERMAL CHARACTERISTICS

| Characteristic                          | Symbol           | 2N2218A<br>2N2219,A | 2N2222,A | Unit |
|---|------------------|---------------------|----------|------|
| Thermal Resistance, Junction to Ambient | R <sub>θJA</sub> | 219                 | 437.5    | °C/W |
| Thermal Resistance, Junction to Case    | R <sub>θJC</sub> | 58                  | 145.8    | °C/W |

## 2N2218A, 2N2219,A★ 2N2222,A★

2N2218, A/2N2219,A  
CASE 79-04  
TO-39 (TO-205AD)  
STYLE 1



A/2N2222,A  
CASE 22-03  
TO-18 (TO-206AA)  
STYLE 1



**GENERAL PURPOSE  
TRANSISTORS**  
NPN SILICON

★2N2219A and 2N2222A  
are Motorola designated  
preferred devices.

### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted.)

| Characteristic   | Symbol               | Min        | Max        | Unit                          |
|--|----------------------|------------|------------|-------------------------------|
| <b>OFF CHARACTERISTICS</b>   |                      |            |            |                               |
| Collector-Emitter Breakdown Voltage<br>(I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 0)  | V <sub>(BR)CEO</sub> | 30<br>40   | —          | Vdc                           |
|  |                      |            |            | Non-A Suffix<br>A-Suffix      |
| Collector-Base Breakdown Voltage<br>(I <sub>C</sub> = 10 μAdc, I <sub>E</sub> = 0)     | V <sub>(BR)CBO</sub> | 60<br>75   | —          | Vdc                           |
|  |                      |            |            | Non-A Suffix<br>A-Suffix      |
| Emitter-Base Breakdown Voltage<br>(I <sub>E</sub> = 10 μAdc, I <sub>C</sub> = 0)       | V <sub>(BR)EBO</sub> | 5.0<br>6.0 | —          | Vdc                           |
|  |                      |            |            | Non-A Suffix<br>A-Suffix      |
| Collector Cutoff Current<br>(V <sub>CE</sub> = 60 Vdc, V <sub>EB(off)</sub> = 3.0 Vdc) | I <sub>CEX</sub>     | —          | 10         | nAdc                          |
|  |                      |            |            | A-Suffix                      |
| Collector Cutoff Current<br>(V <sub>CB</sub> = 50 Vdc, I <sub>E</sub> = 0)             | I <sub>CBO</sub>     | —          | 0.01       | μAdc                          |
| (V <sub>CB</sub> = 60 Vdc, I <sub>E</sub> = 0)   |                      | —          | 0.01       |                               |
| (V <sub>CB</sub> = 50 Vdc, I <sub>E</sub> = 0, T <sub>A</sub> = 150°C)                 |                      | —          | 10         |                               |
| (V <sub>CB</sub> = 60 Vdc, I <sub>E</sub> = 0, T <sub>A</sub> = 150°C)                 |                      | —          | 10         |                               |
| Emitter Cutoff Current<br>(V <sub>EB</sub> = 3.0 Vdc, I <sub>C</sub> = 0)              | I <sub>EBO</sub>     | —          | 10         | nAdc                          |
|  |                      |            |            | A-Suffix                      |
| Base Cutoff Current<br>(V <sub>CE</sub> = 60 Vdc, V <sub>EB(off)</sub> = 3.0 Vdc)      | I <sub>BL</sub>      | —          | 20         | nAdc                          |
|  |                      |            |            | A-Suffix                      |
| <b>ON CHARACTERISTICS</b>  |                      |            |            |                               |
| DC Current Gain<br>(I <sub>C</sub> = 0.1 mAdc, V <sub>CE</sub> = 10 Vdc)               | h <sub>FE</sub>      | 20<br>35   | —          | —                             |
|  |                      |            |            | 2N2218A<br>2N2219,A, 2N2222,A |
| (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc)                                  |                      | 25<br>50   | —          | —                             |
|  |                      |            |            | 2N2218A<br>2N2219,A, 2N2222,A |
| (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc)(1)                                |                      | 35<br>75   | —          | —                             |
|  |                      |            |            | 2N2218A<br>2N2219,A, 2N2222,A |
| (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc,<br>T <sub>A</sub> = -55°C)(1)     |                      | 15<br>35   | —          | —                             |
|  |                      |            |            | 2N2218A<br>2N2219,A, 2N2222,A |
| (I <sub>C</sub> = 150 mAdc, V <sub>CE</sub> = 10 Vdc)(1)                               |                      | 40<br>100  | 120<br>300 | —                             |
|  |                      |            |            | 2N2218A<br>2N2219,A, 2N2222,A |

**2N2218A 2N2219,A 2N2222,A**
**ELECTRICAL CHARACTERISTICS** (continued) ( $T_A = 25^\circ\text{C}$  unless otherwise noted.)

| Characteristic  | Symbol  | Min            | Max         | Unit |
|---|---|----------------|-------------|------|
| ( $I_C = 150 \text{ mAdc}$ , $V_{CE} = 1.0 \text{ Vdc}$ )(1)                                      | 2N2218A<br>2N2219,A, 2N2222,A                 | 20<br>50       | —<br>—      |      |
| ( $I_C = 500 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ )(1)                                       | 2N2219, 2N2222<br>2N2218A<br>2N2219A, 2N2222A | 30<br>25<br>40 | —<br>—<br>— |      |
| Collector-Emitter Saturation Voltage(1)<br>( $I_C = 150 \text{ mAdc}$ , $I_B = 15 \text{ mAdc}$ ) | Non-A Suffix<br>A-Suffix                      | —<br>—         | 0.4<br>0.3  | Vdc  |
| ( $I_C = 500 \text{ mAdc}$ , $I_B = 50 \text{ mAdc}$ )  | Non-A Suffix<br>A-Suffix                      | —<br>—         | 1.6<br>1.0  |      |
| Base-Emitter Saturation Voltage(1)<br>( $I_C = 150 \text{ mAdc}$ , $I_B = 15 \text{ mAdc}$ )      | Non-A Suffix<br>A-Suffix                      | 0.6<br>0.6     | 1.3<br>1.2  | Vdc  |
| ( $I_C = 500 \text{ mAdc}$ , $I_B = 50 \text{ mAdc}$ )  | Non-A Suffix<br>A-Suffix                      | —<br>—         | 2.6<br>2.0  |      |

**SMALL-SIGNAL CHARACTERISTICS**

|  |                                       |              |             |             |                  |
|--|---------------------------------------|--------------|-------------|-------------|------------------|
| Current Gain — Bandwidth Product(2)<br>( $I_C = 20 \text{ mAdc}$ , $V_{CE} = 20 \text{ Vdc}$ , $f = 100 \text{ MHz}$ )                           | All Types, Except<br>2N2219A, 2N2222A | $f_T$        | 250<br>300  | —<br>—      | MHz              |
| Output Capacitance(3)<br>( $V_{CB} = 10 \text{ Vdc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )   |                                       | $C_{obo}$    | —           | 8.0         | pF               |
| Input Capacitance(3)<br>( $V_{EB} = 0.5 \text{ Vdc}$ , $I_C = 0$ , $f = 1.0 \text{ MHz}$ )   | Non-A Suffix<br>A-Suffix              | $C_{ibo}$    | —<br>—      | 30<br>25    | pF               |
| Input Impedance<br>( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )  | 2N2218A<br>2N2219A, 2N2222A           | $h_{je}$     | 1.0<br>2.0  | 3.5<br>8.0  | kohms            |
| ( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )  | 2N2218A<br>2N2219A, 2N2222A           |              | 0.2<br>0.25 | 1.0<br>1.25 |                  |
| Voltage Feedback Ratio<br>( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )                                       | 2N2218A<br>2N2219A, 2N2222A           | $h_{re}$     | —<br>—      | 5.0<br>8.0  | $\times 10^{-4}$ |
| ( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )  | 2N2218A<br>2N2219A, 2N2222A           |              | —<br>—      | 2.5<br>4.0  |                  |
| Small-Signal Current Gain<br>( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )                                    | 2N2218A<br>2N2219A, 2N2222A           | $h_{fe}$     | 30<br>50    | 150<br>300  | —                |
| ( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )  | 2N2218A<br>2N2219A, 2N2222A           |              | 50<br>75    | 300<br>375  |                  |
| Output Admittance<br>( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )  | 2N2218A<br>2N2219A, 2N2222A           | $h_{oe}$     | 3.0<br>5.0  | 15<br>35    | $\mu\text{mhos}$ |
| ( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )  | 2N2218A<br>2N2219A, 2N2222A           |              | 10<br>15    | 100<br>200  |                  |
| Collector Base Time Constant<br>( $I_E = 20 \text{ mAdc}$ , $V_{CB} = 20 \text{ Vdc}$ , $f = 31.8 \text{ MHz}$ )                                 | A-Suffix                              | $rb'C_c$     | —           | 150         | ps               |
| Noise Figure<br>( $I_C = 100 \mu\text{Adc}$ , $V_{CE} = 10 \text{ Vdc}$ ,<br>$R_S = 1.0 \text{ kohm}$ , $f = 1.0 \text{ kHz}$ )                  | 2N2222A                               | NF           | —           | 4.0         | dB               |
| Real Part of Common-Emitter<br>High Frequency Input Impedance<br>( $I_C = 20 \text{ mAdc}$ , $V_{CE} = 20 \text{ Vdc}$ , $f = 300 \text{ MHz}$ ) | 2N2218A, 2N2219A<br>2N2222A           | $Re(h_{je})$ | —           | 60          | Ohms             |

 (1) Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

 (2)  $f_T$  is defined as the frequency at which  $|h_{fe}|$  extrapolates to unity.

 (3) 2N5581 and 2N5582 are Listed  $C_{cb}$  and  $C_{eb}$  for these conditions and values.

ELECTRICAL CHARACTERISTICS (continued) (T<sub>A</sub> = 25°C unless otherwise noted.)

| Characteristic   |   | Symbol         | Min | Max | Unit |
|--|---|----------------|-----|-----|------|
| <b>SWITCHING CHARACTERISTICS</b>   |   |                |     |     |      |
| Delay Time   | (V <sub>CC</sub> = 30 Vdc, V <sub>BE(off)</sub> = -0.5 Vdc, I <sub>C</sub> = 150 mA, I <sub>B1</sub> = 15 mA) (Figure 12) | t <sub>d</sub> | —   | 10  | ns   |
| Rise Time  |   | t <sub>r</sub> | —   | 25  | ns   |
| Storage Time   | (V <sub>CC</sub> = 30 Vdc, I <sub>C</sub> = 150 mA, I <sub>B1</sub> = I <sub>B2</sub> = 15 mA) (Figure 13)                | t <sub>s</sub> | —   | 225 | ns   |
| Fall Time  |   | t <sub>f</sub> | —   | 60  | ns   |
| Active Region Time Constant (I <sub>C</sub> = 150 mA, V <sub>CE</sub> = 30 Vdc) (See Figure 11 for 2N2218A, 2N2219A, 2N2221A, 2N2222A) |   | T <sub>A</sub> | —   | 2.5 | ns   |

FIGURE 1 – NORMALIZED DC CURRENT GAIN

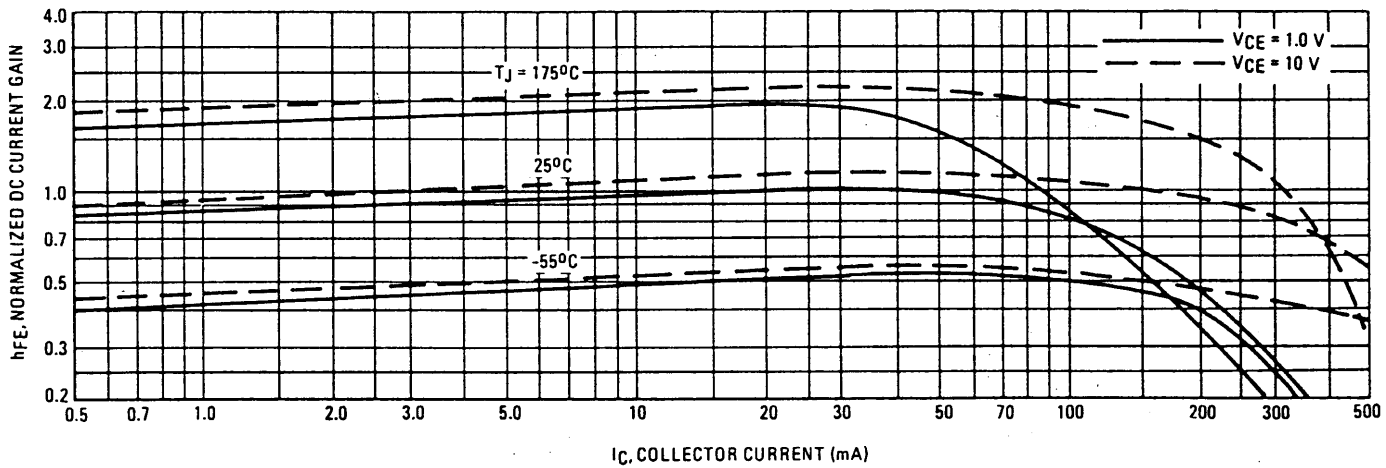
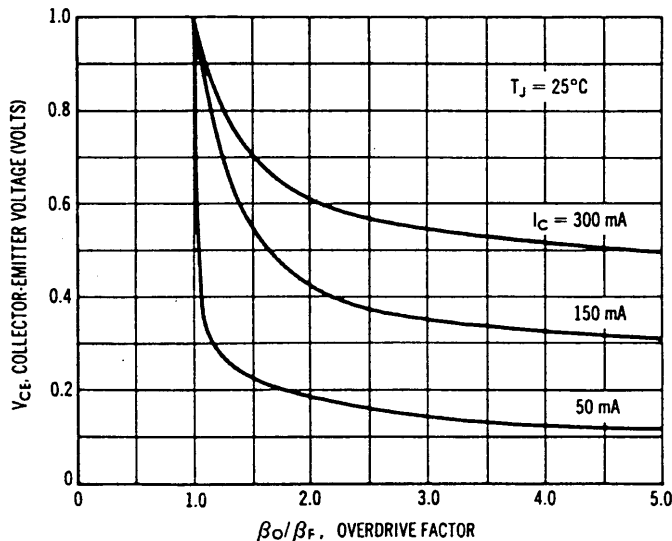


FIGURE 2 – COLLECTOR CHARACTERISTICS IN SATURATION REGION



This graph shows the effect of base current on collector current. β<sub>o</sub> (current gain at the edge of saturation) is the current gain of the transistor at 1 volt, and β<sub>f</sub> (forced gain) is the ratio of I<sub>C</sub>/I<sub>B</sub> in a circuit.

EXAMPLE: For type 2N2219, estimate a base current (I<sub>B</sub>) to insure saturation at a temperature of 25°C and a collector current of 150 mA.

Observe that at I<sub>C</sub> = 150 mA an overdrive factor of at least 2.5 is required to drive the transistor well into the saturation region. From Figure 1, it is seen that h<sub>FE</sub> @ 1 volt is approximately 0.62 of h<sub>FE</sub> @ 10 volts. Using the guaranteed minimum gain of 100 @ 150 mA and 10 V, β<sub>o</sub> = 62 and substituting values in the overdrive equation, we find:

$$\frac{\beta_o}{\beta_f} = \frac{h_{FE} @ 1.0V}{I_C/I_B} \quad 2.5 = \frac{62}{150/I_B} \quad I_B \approx 6.0 \text{ mA}$$

2N2218A 2N2219,A 2N2222,A

FIGURE 3 — "ON" VOLTAGES

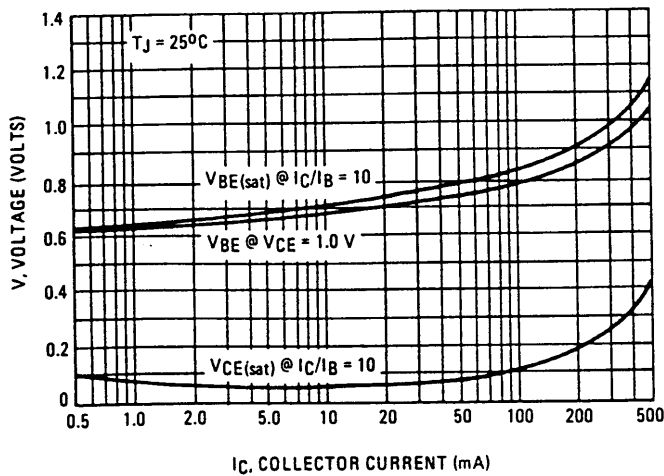
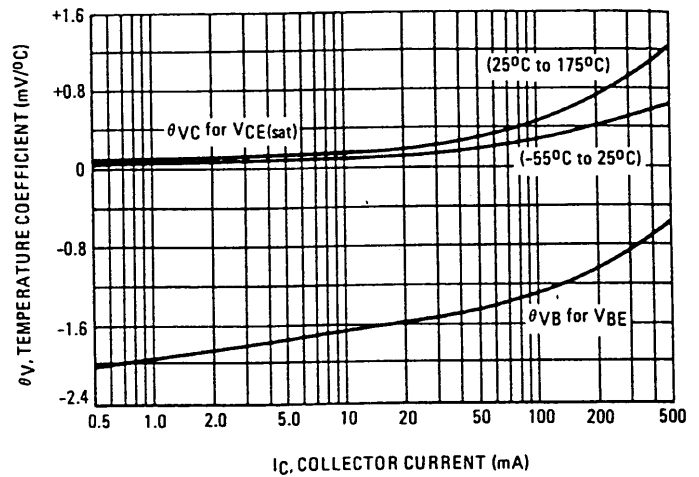


FIGURE 4 — TEMPERATURE COEFFICIENTS



h PARAMETERS

$V_{CE} = 10 \text{ Vdc}$ ,  $f = 1.0 \text{ kHz}$ ,  $T_A = 25^\circ\text{C}$

This group of graphs illustrates the relationship between  $h_{fe}$  and other "h" parameters for this series of transistors. To obtain these curves, a high-gain and a low-gain unit were selected and the same units were used to develop the correspondingly numbered curves on each graph.

FIGURE 5 — INPUT IMPEDANCE

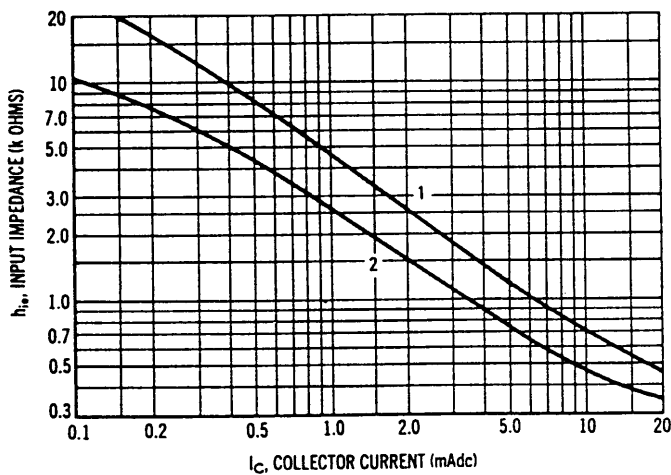


FIGURE 6 — VOLTAGE FEEDBACK RATIO

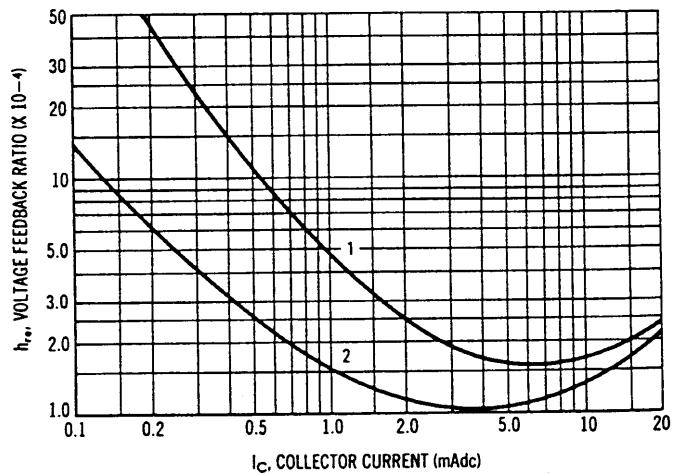


FIGURE 7 — CURRENT GAIN

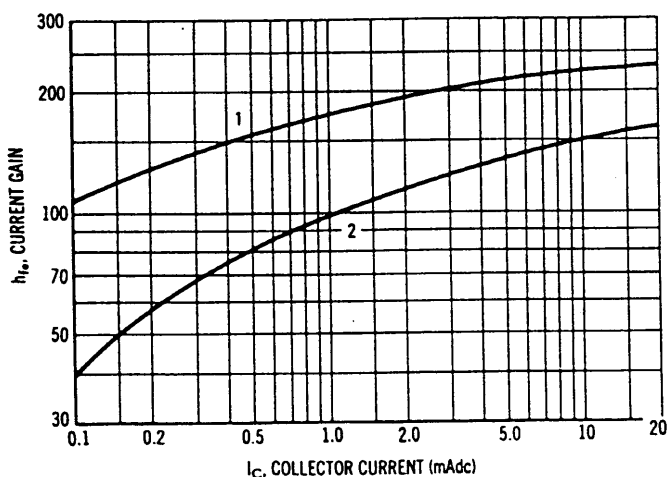
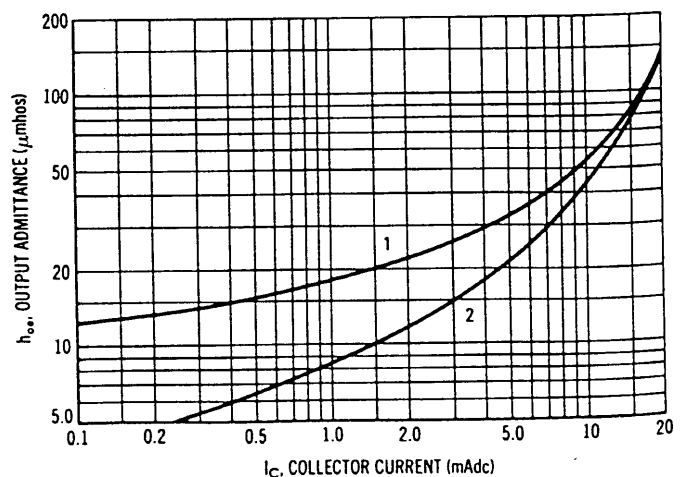


FIGURE 8 — OUTPUT ADMITTANCE



SWITCHING TIME CHARACTERISTICS

FIGURE 9 — TURN-ON TIME

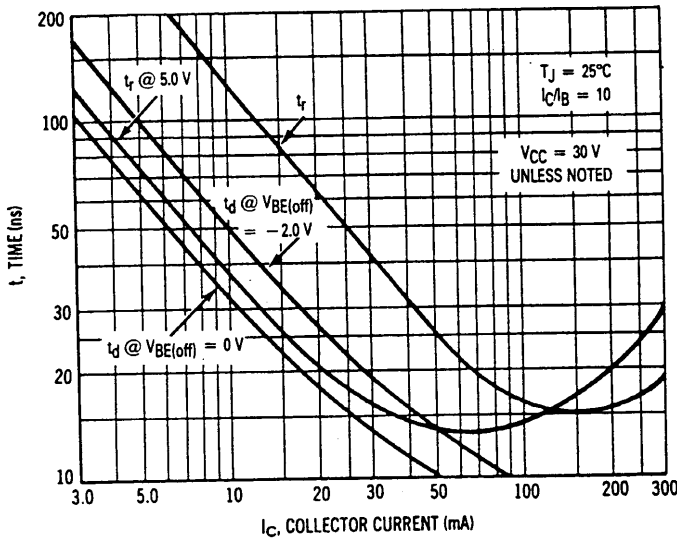


FIGURE 10 — CHARGE DATA

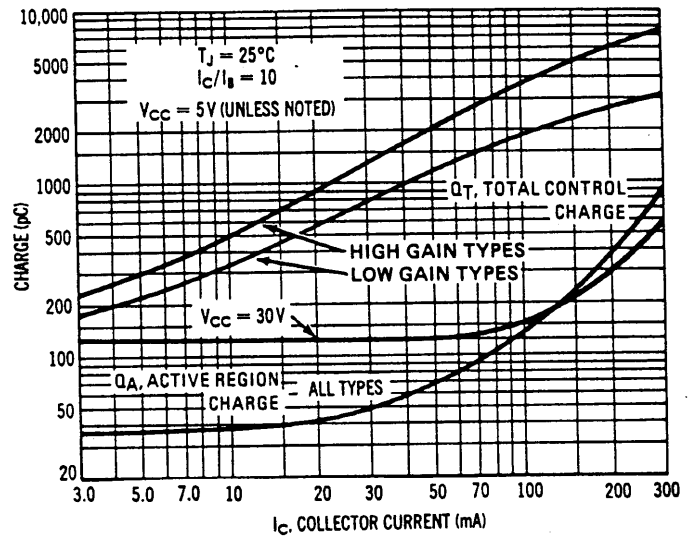


FIGURE 11 — TURN-OFF BEHAVIOR

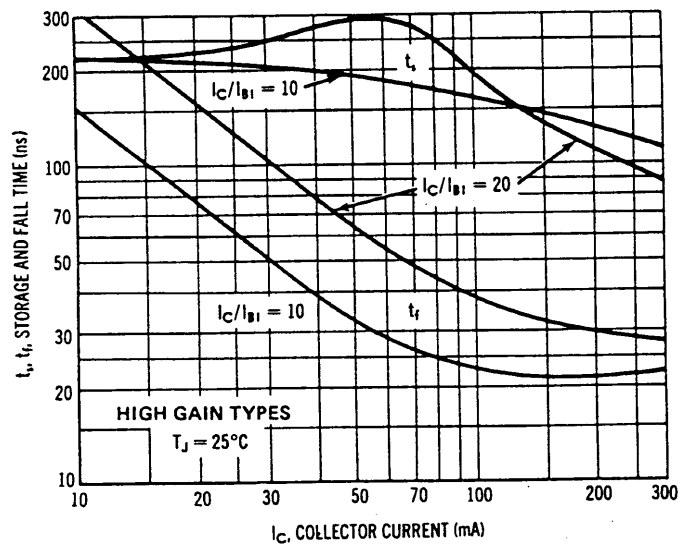
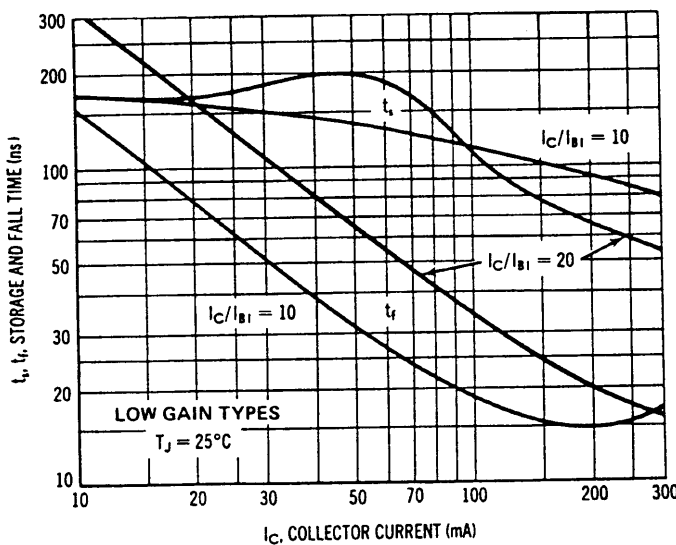


FIGURE 12 — DELAY AND RISE TIME EQUIVALENT TEST CIRCUIT

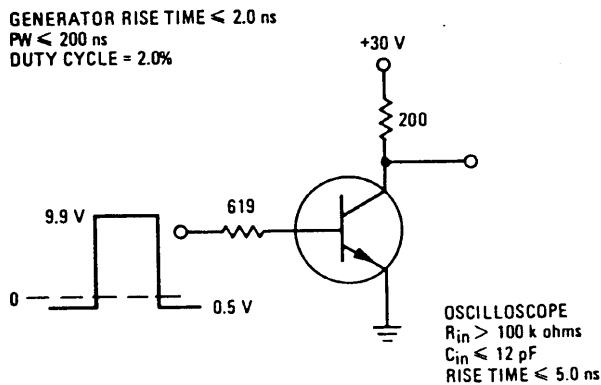


FIGURE 13 — STORAGE TIME AND FALL TIME EQUIVALENT TEST CIRCUIT

